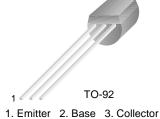


# KSC1674

# TV PIF Amplifier, FM Tuner RF Amplifier, Mixer, Oscillator

- High Current Gain Bandwidth Product : f<sub>T</sub>=600MHz (TYP.)
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



# **NPN Epitaxial Silicon Transistor**

### Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>CBO</sub>	Collector-Base Voltage	30	V
V <sub>CEO</sub>	Collector-Emitter Voltage	20	V
V <sub>EBO</sub>	Emitter-Base Voltage	4	V
I <sub>C</sub>	Collector Current	20	mA
P <sub>C</sub>	Collector Power Dissipation	250	mW
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

### Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =10μA, I <sub>E</sub> =0	30			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C=5$ mA, $I_B=0$	20			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =10μA, I <sub>C</sub> =0	4			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}$ =30V, $I_E$ =0			0.1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB}$ =4V, $I_{C}$ =0			0.1	μΑ
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =6V, I <sub>C</sub> =1mA	40		240	
V <sub>BE</sub> (on)	Base-Emitter On Voltage	V <sub>CE</sub> =6V, I <sub>C</sub> =1mA		0.72		V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =1mA		0.1	0.3	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =6V, I <sub>C</sub> =1mA	400	600		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =6V, I <sub>E</sub> =0, f=1MHz		1.2		pF
C <sub>c-rbb'</sub>	Collector-Base Time Constant	V <sub>CE</sub> =6V, I <sub>C</sub> =1mA f=31.9MHz		12	15	ps
NF	Noise Figure	$V_{CE}$ =6V, $I_{C}$ =1mA $R_{S}$ =50 $\Omega$ , f=100MHz		3.0	5.0	dB

## **h**<sub>FE</sub> Classification

Classification	R	0	Υ
h <sub>FE</sub>	40 ~ 80	70 ~ 140	120~ 240

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Rev. B2, November 2002

# **Typical Characteristics**

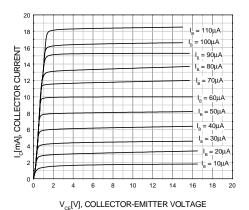


Figure 1. Static Characteristic

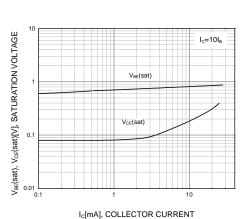


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

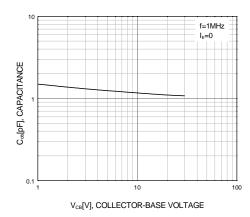
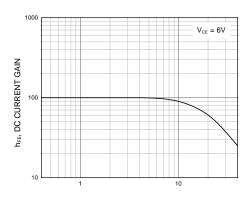


Figure 5. Collector Output Capacitance



I<sub>c</sub>[mA], COLLECTOR CURRENT

Figure 2. DC current Gain

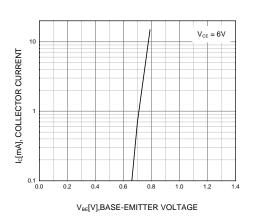


Figure 4. Base-Emitter On Voltage

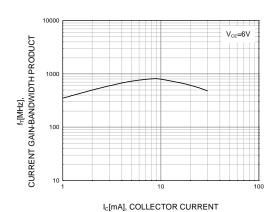


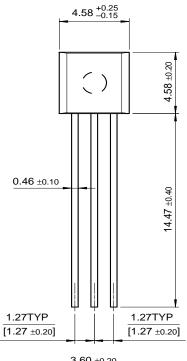
Figure 6. Current Gain Bandwidth Product

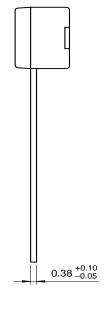
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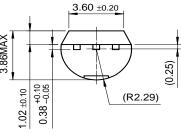


# **Package Dimensions**

TO-92







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CoolFET™	FASTr™	MicroFET™	PowerTrench <sup>®</sup>	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E <sup>2</sup> CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	$I^2C^{TM}$	$OCX^{TM}$	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
The Power Franc	hise™	OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	VCX™
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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